

APPROVAL SHEET

MULTILAYER CERAMIC CAPACITORS

Microwave Capacitors Series (RT)

Qualified to AEC-Q200

0402 Size (25V to 50V)

NP0 Dielectric

Halogen Free & RoHS Compliance

*Contents in this sheet are subject to change without prior notice.

1. DESCRIPTION

MLCC consists of a conducting material and electrodes. To manufacture a chip-type SMT and achieve miniaturization, high density and high efficiency, ceramic condensers are used.

WTC's RT series MLCC is used at high frequencies generally have a small temperature coefficient of capacitance, typical within the ±30ppm/C required for NP0 (C0G) classification and have excellent conductivity internal electrode. Thus, WTC RT series MLCC will be with the feature of low ESR and high Q characteristics, stability and reliability. Besides, RT series MLCC is tighten controlling in quality in line to assure quality performance in automotive applications. The RT series is AEC-Q200 compliant.

2. FEATURES

- a. High Q and low ESR performance at high frequency.
- b. High reliability: AEC-Q200.
- c. Ultra low capacitance to 0.1pF.
- d. Can offer high precision tolerance to ±0.05pF.
- e. Quality improvement of telephone calls for low power loss and better performance.

3. APPLICATIONS

- a. Automotive, power supply and related industries. .
- The other mechanical stress concerned products or the set having a high probability of fall.
- Prevention of ceramic body cracks by board bending.
- d. RF module: Power amplifier, VCO.
- e. Tuners.

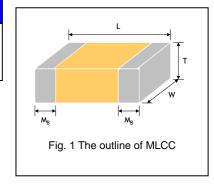
4. HOW TO ORDER

<u>RT</u>	<u>15</u>	<u>N</u>	<u>101</u>	<u>J</u>	<u>250</u>	<u>C</u>	I
<u>Series</u>	Size	Dielectric	<u>Capacitance</u>	<u>Tolerance</u>	Rated voltage	<u>Termination</u>	Packaging style
RT= Microwave MLCC (with AEC-Q200 qualification)	15 =0402 (1005)	N=NPO	Two significant digits followed by no. of zeros. And R is in place of decimal point. eg.: 0R5=0.5pF 1R0=1.0pF 100=10x10 ¹	A=±0.05pF B=±0.1pF C=±0.25pF D=±0.5pF F=±1% G=±2% J=±5%	Two significant digits followed by no. of zeros. And R is in place of decimal point. 250=25 VDC 500=50 VDC		T=7" reeled G=13" reeled

5. EXTERNAL DIMENSIONS

Size Inch (mm)	L (mm)	W (mm)	T (mm)/Symb	ol	Remark	M _B (mm)
0402 (1005)	1.00±0.08	0.50±0.08	0.50±0.08	N	#	0.25 +0.05/-0.10

[#] Reflow soldering only is recommended.



6. GENERAL ELECTRICAL DATA

Dielectric	NP0
Size	0402
Capacitance*	0.1pF to 56pF
Capacitance tolerance	Cap≤5pF ^{#1} : A (±0.05pF), B (±0.1pF), C (±0.25pF) 5pF <cap<10pf: (±0.1pf),="" (±0.25pf),="" (±0.5pf)="" (±1%),="" (±2%),="" (±5%)<="" b="" c="" cap≥10pf:="" d="" f="" g="" j="" th=""></cap<10pf:>
Rated voltage (WVDC)	25V, 50V
Q*	Cap<30pF:Q≥400+20C; Cap≥30pF:Q≥1000
Insulation resistance at Ur ≥10GΩ or RxC≥100Ω-F whichever is smaller.	
Operating temperature -55 to +125℃	
Capacitance change	±30ppm/℃
Termination	Ni/Sn (lead-free termination)

^{#1:} Cap= 0.1pF product only provide B tolerance.

Apply 1.0±0.2Vrms, 1.0MHz±10% for Cap≤1000pF and 1.0±0.2Vrms, 1.0kHz±10% for Cap>1000pF.



 $^{^{\}star}$ Measured at the conditions of 25°C ambient temper ature and 30~70% related humidity.

7. CAPACITANCE RANGE



	DIELECTRIC		NI	20	
	SIZE		04		
P	ATED VOLTAGE (VDC)		25	50	Tolerance
	0.1pF (0l		N N	N	В
	0.2pF (0l		N	N	A, B
	0.3pF (0l		N	N	A, B
	0.4pF (0l		N	N	A, B
	0.5pF (0l 0.6pF (0l		N N	N N	A, B, C A, B, C
	0.7pF (0)		N	N	A, B, C
	0.75pF (R		N	N	A, B, C
	0.8pF (0l	R8)	N	N	A, B, C
	0.9pF (0)		N N	N	A, B, C
	1.0pF (1) 1.1pF (1)		N N	N N	A, B, C A, B, C
	1.1pF (11		N N	N	A, B, C
	1.3pF (1)		N	N	A, B, C
	1.5pF (1)		N	N	A, B, C
	1.6pF (1)	R6)	N	N	A, B, C
	1.8pF (1)		N N	N N	A, B, C A, B, C
	2.0pF (2l 2.2pF (2l		N N	N N	A, B, C A, B, C
	2.4pF (2)		N	N N	A, B, C
	2.7pF (2l	R7)	N	N	A, B, C
	3.0pF (3)		N	N	A, B, C
	3.3pF (3l		N N N	FI NO SI	A, B, C
	3.6pF (3l 3.9pF (3l		N/	NA 12 N	A, B, C A, B, C
	4.0pF (4l		N -	政历系。	A, B, C
	4.3pF (4l		Z.M.	N/S	A, B, C
	4.7pF (4l		717 N 43	N	A, B, C
	5.0pF (5l		N _A	N Y	A, B, C
	5.1pF (5) 5.6pF (5)		N N	S AN	B, C, D B, C, D
မွ	6.0pF (6l		N PASSTV	SYSTEM ALL NANCE	B, C, D
Capacitance	6.2pF (6l		SNZ PASSIVE	N S	B, C, D
aci	6.7pF (6l		N	N 2 E	B, C, D
Зар	6.8pF (6)		N N	N N	B, C, D
J	7.0pF (7) 7.5pF (7)		N N	N N	B, C, D B, C, D
	8.0pF (8l		N/I/o Ch	N N	B, C, D
	8.2pF (8l		N M	VOIDE N	B, C, D
	9.0pF (9)		N CCHIN	OCA CODDUDINATIVE	B, C, D
	9.1pF (9) 10pF (1		N N	N N	B, C, D
	11pF (1		N N	N N	F, G, J F, G, J
	12pF (1		N	N	F, G, J
	13pF (1	30)	N	N	F, G, J
	15pF (1		N	N	F, G, J
	16pF (1 18pF (1		N N	N N	F, G, J F, G, J
	20pF (2		N N	N N	F, G, J
	22pF (2	220)	N	N	F, G, J
	24pF (2	(40)	N	N	F, G, J
	27pF (2		N	N	F, G, J
	30pF (3 33pF (3		N N	N N	F, G, J F, G, J
	36pF (3		N N	N	F, G, J
	39pF (3	90)	N	N	F, G, J
	43pF (4	30)	N	N	F, G, J
	47pF (4		N	N	F, G, J
	51pF (5 56pF (5		N N		F, G, J F, G, J
	62pF (6				1, 0, 0
	68pF (6	(08			
	75pF (7	'50)			
	82pF (8	20)			
	91pF (9 100pF (1	01)			
			he symbol of product thicknes	ee .	1

^{1.} The letter in cell is expressed the symbol of product thickness.

^{2.} For more information about products with special capacitance or other data, please contact WTC local representative



8. PACKAGING STYLE AND QUANTITY

Size	Thiskness (mm)/S	umb ol	Paper tape			
Size	ize Thickness (mm)/Symbol		7" reel	13" reel		
0402 (1005)	0.50±0.08	N	10,000	50,000		

Unit: pieces





9. RELIABILITY TEST CONDITIONS AND REQUIREMENTS

No.	AEC-Q200 Test Item	AEC-Q200 Test Condition	Requirements
1.	Pre-and Post-Stress Electrical Test		
2.	High Temperature Exposure (Storage) MIL-STD-202 Method 108	* Test temp.: 150±3℃ * Unpowered. * Test time: 1000+24/-0 hrs. * Measurement to be made after keeping at room temp. for 24±2 hrs.	* No remarkable damage. * Cap change: NPO: within ±2.5% or ±0.25pF whichever is larger. * Q. value: NPO: Cap≥30pF, Q≥1000; Cap<30pF, Q≥400+20C. * I.R.: ≥10GΩ or RxC≥500Ω-F whichever is smaller.
3.	Temperature Cycling JESD22 Method JA-104	* Conduct 1000 cycles according to the temperatures and time.	* No remarkable damage. * Cap change: NPO: within ±2.5% or 0.25pF whichever is larger. * Q. value: NPO: Cap≥30pF, Q≥1000; Cap<30pF, Q≥400+20C. * I.R.: ≥10GΩ or RxC≥500Ω-F whichever is smaller.
4.	Destructive Physical Analysis EIA-469	Per EIA-469	No defects or abnormalities
5.	Moisture Resistance MIL-STD-202 Method 106	* Test temp.: 25~65°C * Humidity: 80~100% RH * Test time: 10 cycles, t=24hrs/cycle. * Measurement to be made after keeping at room temp. for 24±2 hrs.	* No remarkable damage. * Cap change : NPO; within ±3.0% or 0.30pF whichever is larger * Q. value: NPO: More than 30pF Q≥350; 10pF≤C≤30pF, Q≥275+2.5C Less than 10pF Q≥200+10C * I.R.: ≥10GΩ or RxC≥500Ω-F whichever is smaller.
6.	Biased Humidity MIL-STD-202 Method 103	* Test temp.: 85±3°C * Humidity: 85%RH * Test time: 1000+24/-0 hrs. * To apply voltage: rated voltage and 1.3~1.5Vdc. (add 100k ohm resistor) * Measurement to be made after keeping at room temp. for 24±2 hrs.	* No remarkable damage. * Cap change; NPO: within ±3.0% or 0.30pF whichever is larger. * Q. value: NPO: C≥30pF , Q≥200 ; C<30pF , Q≥100+10/3C * I.R.: ≥1GΩ or RxC≥50Ω-F whichever is smaller.
7.	Operational Life MIL-STD-202 Method 108	* Test temp.: 125±3℃ * To apply voltage: 200% of rated voltage. * Test time: 1000+24/-0 hrs. * Measurement to be made after keeping at room temp. for 24±2 hrs.	* No remarkable damage. * Cap change: NPO: within ±3.0% or ±0.3pF whichever is larger * Q. value: NPO: More than 30pF, Q≥350; 10pF≤C<30pF, Q≥275+2.5C Less than 10pF, Q≥200+10C * I.R.: ≥1GΩ or RxC≥50Ω-F whichever is smaller.
8.	External Visual MIL-STD-883 Method 2009	Visual inspection	No remarkable defect.
9.	Physical Dimension JESD22 Method JB-100	Using by calipers	Within the specified dimensions

^{* &}quot;Room condition" Temperature: 15 to 35°C, Relative humidity: 25 to 75%, Atmospheric pressure: 86 to 106kPa.



No.	AEC-Q200 Test Item	AEC-Q200 Test Condition	Requirements
10.	Resistance to	* Temperature: 25±5℃	* No remarkable damage.
	Solvents	* Time: 3+0.5/-0 min.	* Cap.: within the specified tolerance.
	MIL-STD-202	* Solvent: Iso-propyl alcohol.	* Q. value: NPO: Cap≥30pF, Q≥1000 ; Cap<30pF, Q≥400+20C.
	Method 215		* I.R.: ≥10GΩ or RxC≥500Ω-F whichever is smaller.
11.	Mechanical Shock	* Peak value: 1500g's.	* No remarkable damage.
	MIL-STD-202	* Wave: 1/2 sine.	* Cap.: within the specified tolerance.
	Method 213	* Velocity: 15.4 ft/sec	* Q. value: NPO: Cap≥30pF, Q≥1000 ; Cap<30pF, Q≥400+20C.
		* Three shocks in each direction should be applied	* I.R.: ≥10GΩ or RxC≥500Ω-F whichever is smaller.
		along	
		3 mutually perpendicular axes of the test specimen	
		(18 shocks)	
12.	Vibration	* Vibration frequency: 10~2000 Hz/min.	* No remarkable damage.
	MIL-STD-202	(5g's for 20 min)	* Cap.: within the specified tolerance.
	Method 204	* Total amplitude: 1.5mm	* Q. value: NPO:Cap≥30pF, Q≥1000 ; Cap<30pF, Q≥400+20C.
		* 12 cycles each of 3 orientations (36 times)	* I.R.: ≥10GΩ or RxC≥500Ω-F whichever is smaller.
13.	Resistance to	* Solder temperature: 270±5℃	* No remarkable damage.
	Soldering Heat	* Dipping time: 10±1 sec	* Cap change: NPO: within ±2.5% or 0.25pF whichever is larger
	MIL-STD-202	* Measurement to be made after keeping at room	* Q. value: NPO: Cap≥30pF, Q≥1000 ; Cap<30pF, Q≥400+20C.
	Method 210	temp. for 24±2 hrs.	i * I.R.: ≥10GΩ or RxC≥500Ω-F whichever is smaller.
14	Thermal Shock	* Conduct 300 cycles according to the temperatures	* No remarkable damage.
	MIL-STD-202	and time.	* Cap change: NPO: within ±2.5% or 0.25pF whichever is larger.
	Method 107	Step Temp. (°C) Time (min.)	* Q. value: NPO: Cap≥30pF, Q≥1000 ; Cap<30pF, Q≥400+20C.
		1 -55°C +0/-3 15±3	
		2 +125°C +3/-0 / 15±3	
			50
		* Max. transfer time: 20 sec.	
		* Measurement to be made after keeping at room	
15	ESD	temp. for 24±2 hrs.	AALLTANGE
13.		Per AEC-Q200-002	* No remarkable damage.
	AEC-Q200-002	量る	* Cap.: within the specified tolerance.
		S. O.	* Q. value: NPO: Cap≥30pF, Q≥1000 ; Cap<30pF, Q≥400+20C.
		0,2	* I.R.: ≥10GΩ or RxC≥500Ω-F whichever is smaller.
16.	Solderability	* Condition A	All terminations shall exhibit a continuous solder coating free from
	J-STD-002	" 1601	defects from a minimum of 95% of the critical surface area of any individual
	JESD22-B102E	immersed for 5±0.5 sec in solder bath at 235±5°C.	termination.
		* Condition B	(Oth
		Un-mounted chips steam 8 hrs then completely	
		immersed for 10±1sec in solder bath at 215+5/-0°C.	
		* Condition C	
		Un-mounted chips steam 8 hrs then completely	
		immersed for 10±1 sec. in solder bath at 260+0/-5°C.	

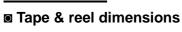
^{* &}quot;Room condition" Temperature: 15 to 35°C, Relative humidity: 25 to 75%, Atmospheric pressure: 86 to 106kPa.

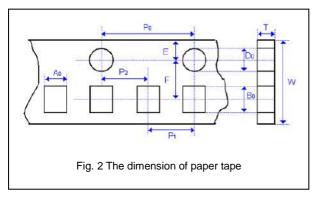
No.	AEC-Q200	AEC-Q200 Test Condition	Requirements		
	lest Item		4		
17.	Electrical	* Capacitance	* Capacitance within the specified tolerance.		
	Characterization	* Q. value	* Q. value: NPO: Cap≥30pF, Q≥1000 ; Cap<30pF, Q≥400+20C.		
		Cap≤1000pF 1.0±0.2Vrms, 1MHz±10%			
		Cap>1000pF 1.0±0.2Vrms, 1KHz±10%			
		* Test temp.: Room Temperature.			
		* Insulation Resistance	* IR. ≥10GΩ or RxC≥500Ω-F whichever is smaller.		
		To apply rated voltage(500V max.) for max. 120 sec			
		* Test temp.: Room Temperature			
		* Dielectric Strength	* Dielectric strength		
		To apply voltage:	No evidence of damage or flash over during test.		
		≦100 ≥2.5 times VDC			
		, duration 1~5 sec,			
		charge and discharge current less than 50mA.			
		* Temperature Coefficient (with no electrical load)	* Temperature Coefficient		
		Operation temperature: -55~125℃ at 25℃	Capacitance Change: NPO: Within ±30ppm/℃		
18.	Board Flex	* The middle part of substrate shall be pressurized by	* No remarkable damage.		
	AEC-Q200-005	means of the pressurizing rod at a rate of about 1	* Cap change: NPO: within ±5% or 0.5pF whichever is larger		
		mm per second until the deflection becomes 5 mm	(This capacitance change means the change of capacitance under specified		
		and then the pressure shall be maintained for 60±1	flexure of substrate from the capacitance measured before the test.)		
		sec.			
		* Measurement to be made after keeping at room			
		temp. for 24±2 hrs.			
19.	Terminal Strength	* Pressurizing force :	* No remarkable damage or removal of the terminations.		
	AEC-Q200-006	2N (0201 & 0402), 10N(0603), 18N(≥0805).	* Capacitance within the specified tolerance.		
		* Test time: 60±1 sec.	* Q. value: NPO: Cap≥30pF, Q≥1000 ; Cap<30pF, Q≥400+20C.		
		PASSIVE SYSTEM	ALLIANCE		
20	Beam Load Test	* Break strength test	The chip endure following force		
	AEC-Q200-003	* Beam speed: 2.5±0.25 mm/sec	* Chip length ≤2.5mm; Thickness >0.5mm (20N), ≤0.5mm (8N)		
			* Chip length ≥3.2mm: Thickness ≥1.25mm (54.5N), <1.25mm (15N)		
		Chi la			
21	ESR	The ESR should be measured at room temperature			
		and tested at frequency 1±0.1 GHz.	0402		
		CONVOLOGY COF	0.1pF≤Cap≤1pF:< 350mΩ/pF		
		-501001	1pF <cap≤5pf:< 250mω<="" 300mω="" 5pf<cap≤100pf:<="" th=""></cap≤5pf:<>		
			5pF <cap≤100pf:< 250mω<="" th=""></cap≤100pf:<>		

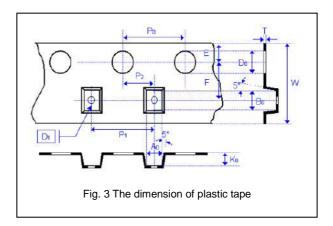
 $^{^{\}star}$ "Room condition" Temperature: 15 to 35°C, Relative humidity: 25 to 75%, Atmospheric pressure: 86 to 106kPa.

Approval Sheet

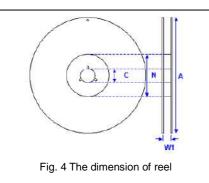
APPENDIXES





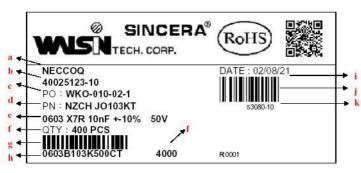


Size	0201	0402	0603		0805			1206			1210	
Thickness	L	N,E	S,H,X	A,H	В,Т	D,I	В,Т	C,J,D	G,P	Т	C,D,G,K	М
A ₀	0.40 +/-0.10	0.70 +/-0.20	1.05 +/-0.30	1.50 +/-0.20	1.50 +/-0.20	< 1.80	1.90 +/-0.50	< 2.00	<2.30	< 3.05	< 3.05	< 3.20
B ₀	0.70 +/-0.10	1.20 +/-0.20	1.80 +/-0.30	2.30 +/-0.20	-2.30 +/-0.20	< 2.70	3.50 +/-0.50	< 3.70	< 4.00	< 3.80	< 3.80	<4.00
Т	≦0.55	≦0.80	≦1.20	≦1.15	≦1.20	0.23 +/-0.1	≦1.20	0.23 +/-0.1	0.23 +/-0.1	0.23 +/-0.1	0.23 +/-0.1	0.23 +/-0.1
K ₀	-	-	-/14	, L ,	も版:	< 2.50	754	< 2.50	< 2.50	< 1.50	< 2.50	< 3.20
W	8.00	8.00	8.00	8.00	8.00	8.00	8.00	8.00	8.00	8.00	8.00	8.00
	+/-0.30	+/-0.30	+/-0.30	+/-0.30	+/-0.30	+/-0.30	+/-0.30	+/-0.30	+/-0.30	+/-0.30	+/-0.30	+/-0.30
P ₀	4.00	4.00	4.00	4.00	4.00	4.00	4.00	4.00	4.00	4.00	4.00	4.00
	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10
10xP ₀	40.00	40.00	40.00	40.00	40.00	40.00	40.00	40.00	40.00	40.00	40.00	40.00
	+/-0.10	+/-0.10	+/-0.20	+/-0.20	+/-0.20	+/-0.20	+/-0.20	+/-0.20	+/-0.20	+/-0.20	+/-0.20	+/-0.20
P ₁	2.00	2.00	4.00	4.00	4.00	4.00	4.00	4.00	4.00	4.00	4.00	4.00
	+/-0.05	+/-0.05	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10
P ₂	2.00	2.00	2.00	2.00	2.00	2.00	2.00	2.00	2.00	2.00	2.00	2.00
	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05
D ₀	1.50	1.50	1.50	1.50	1.50	1.50	1.50	1.50	1.50	1.50	1.50	1.50
	+0.1/-0	+0.1/-0	+0.1/-0	+0.1/-0	+0.1/-0	+0.1/-0	+0.1/-0	+0.1/-0	+0.1/-0	+0.1/-0	+0.1/-0	+0.1/-0
D ₁	-	-		%	-	1.00 +/-0.10	(E	1.00 +/-0.10	1.00 +/-0.10	1.00 +/-0.10	1.00 +/-0.10	1.00 +/-0.10
Е	1.75	1.75	1.75	1.75	1.75	1.75	1.75	1.75	1.75	1.75	1.75	1.75
	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10	+/-0.10
F	3.50	3.50	3.50	3.50	3.50	3.50	3.50	3.50	3.50	3.50	3.50	3.50
	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05	+/-0.05



Size	0201, 0402, 0603, 0805, 1206, 1210					
Reel size	7"	10"	13"			
С	13.0±0.5	13.0±0.5	13.0±0.5			
W ₁	10.0±1.5	10.0±1.5	10.0±1.5			
Α	178.0±2.0	250.0±2.0	330.0±2.0			
N	60.0+1.0/-0	50 min	50 min			

Example of customer label

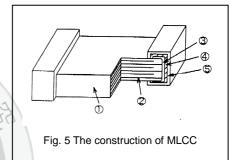


^{*}Customized label is available upon request

- a. Customer name
- b. WTC order series and item number
- c. Customer P/O
- d. Customer P/N
- e. Description of product
- f. Quantity
- g. Bar code including quantity & WTC P/N or customer
- h. WTC P/N
- i. Shipping date
- . Order bar code including series and item numbers
- k. Serial number of label

Constructions

No.	Nam	ne	NP0
①	Ceramic r	material	Hi-Q dielectric ceramic
2	Inner ele	ctrode	Cu
3		Inner layer	Cu + Conductive Resin
4	Termination	Middle layer	Ni Ni
(5)		Outer layer	Sn (Matt)



PASSIVE SYSTEM ALLIANCE

Storage and handling conditions

- (1) To store products at 5 to 40°C ambient temperature and 20 to 70%, related humidity conditions; MSL Level 1.
- (2) The product is recommended to be used within one year after shipment. Check solderability in case of shelf life extension is needed.

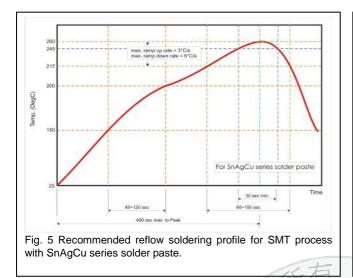
Cautions:

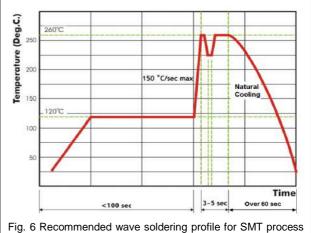
- a. The corrosive gas reacts on the terminal electrodes of capacitors, and results in the poor solderability. Do not store the capacitors in the ambience of corrosive gas (e.g., hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas etc.)
- b. In corrosive atmosphere, solderability might be degraded, and silver migration might occur to cause low reliability.
- c. Due to the dewing by rapid humidity change, or the photochemical change of the terminal electrode by direct sunlight, the solderability and electrical performance may deteriorate. Do not store capacitors under direct sunlight or dewing condition. To store products on the shelf and avoid exposure to moisture.

Approval Sheet

■ Recommended soldering conditions

The lead-free termination MLCCs are not only to be used on SMT against lead-free solder paste, but also suitable against lead-containing solder paste. If the optimized solder joint is requested, increasing soldering time, temperature and concentration of N_2 within oven are recommended.





with SnAgCu series solder.

PASSIVE SYSTEM ALLIANCE SO STORY CORPORATION THE PASSIVE SYSTEM ALLIANCE SYST